

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent application:

IAKAMURA et al.

Atty. Docket: 160-356

erial No.:

09/809,038

Group Unit:

TBA

Filed:

March 16, 2001

Examiner:

TBA

For:

NITRIDE SEMICONDUCTOR LIGHT-EMITTING DEVICE

April 13, 2001

Assistant Commissioner for Patents Washington, DC 20231

PRELIMINARY AMENDMENT

Sir:

Prior to substantive examination and prior to calculating the fee, please amend the above-identified patent application as follows.

IN THE CLAIMS:

Please cancel Claims 1-62 without prejudice or disclaimer as to the subject matter contained therein.

Please add the following new Claims 63-71 as follows:

--63. (New) A nitride semiconductor light-emitting device comprising: an n-type layer comprising an n-type GaN or and n-type nitride semiconductor containing indium and gallium;

a first p-type clad layer comprising a p-type nitride semiconductor containing indium and gallium;